

# **Application Note AN-1103**

# IRS2103 and IR2103 Comparison

By Jason Nguyen, Min Fang, David New

#### **Table of Contents**

Introduction	Page
Introduction	1
Block Diagram	2
Electrical Characteristic Differences	3
Figures	3
Summary	8

#### Introduction

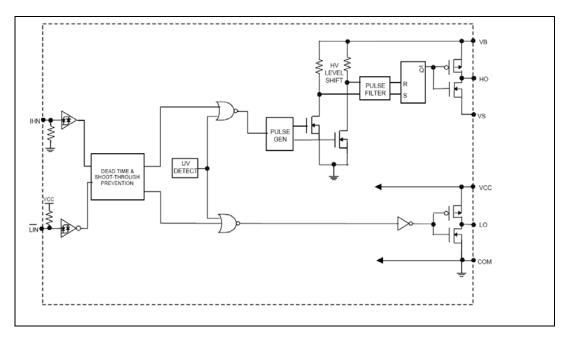
The IRS2103 is a new HVIC product that replaces the IR2103 and is pin-to-pin compatible with its corresponding predecessor. In many cases, little or no change is necessary to use the new product. This application note describes the various differences between the IRS2103 and the IR2103 HVICs.

The IRS2103 is a high voltage, high speed power MOSFET and IGBT driver with independent high and low side referenced output channels. Proprietary HVIC and latch immune CMOS technologies enable ruggedized monolithic construction. The logic input is compatible with standard CMOS or LSTTL outputs, down to 3.3 V logic. The output drivers feature a high pulse current buffer stage designed for minimum driver cross-conduction. The floating channel can be used to drive an N-channel power MOSFET or IGBT in the high side configuration which operates up to 600 V.

www.irf.com AN-1103



## **Block Diagram**



The IRS2103 and the IR2103 share the same block diagram. The functionality of the two ICs is the same.

#### **Electrical Characteristic Differences**

All measurement conditions remain unchanged unless noted. Parameters not mentioned in this document have not changed.

### **Absolute Maximum Ratings**

There are no changes in the Absolute Maximum Ratings.

### **Recommended Operating Conditions**

There are no changes in the Recommended Operating Conditions.

www.irf.com AN-1103 2



### **Dynamic Electrical Characteristics**

Parameter		IR2	103	IRS			
Symbol	Definition	typ	max	typ	max	Units	
t <sub>r</sub>	Turn-on rise time	100	170	70	170	ns	
t <sub>f</sub>	Turn-off fall time	50	90	35	90	115	

The IRS2103 has faster rise and fall times when compared to the IRS2103.

#### **Static Electrical Characteristics**

Parameter		IR2103			IRS2103			
Symbol	Definition	min	typ	max	min	typ	max	Units
$V_{IH}$	Logic "1" input voltage (V <sub>CC</sub> = 10 V to 20 V)	3	-	-	2.5	-	-	
$V_{IL}$	Logic "0" input voltage (V <sub>CC</sub> = 10 V to 20 V)	-	-	0.8	-	-	0.8	
V <sub>OH</sub>	High level output voltage, V <sub>BIAS</sub> - V <sub>o</sub>	-	-	0.1	-	0.05	0.2	V
VOH		Io = 0 mA		lo = 2 mA				
Vol	Low level output voltage, V <sub>O</sub>	-	-	0.1	-	0.02	0.1	
V OL	Low level output voltage, v <sub>0</sub>	lo =		Io = 0 mA		lo = 2 m	ıA	
I <sub>O+</sub>	Output high short circuit pulsed current (V <sub>O</sub> = 0 V, VIN=Logic "1", PW <= 10us)	130	210	-	130	290	-	mA
I <sub>O-</sub>	Output low short circuit pulsed current (V <sub>O</sub> = 15 V, VIN = Logic "0", PW <= 10us)	270	360	-	270	600	-	IIIA

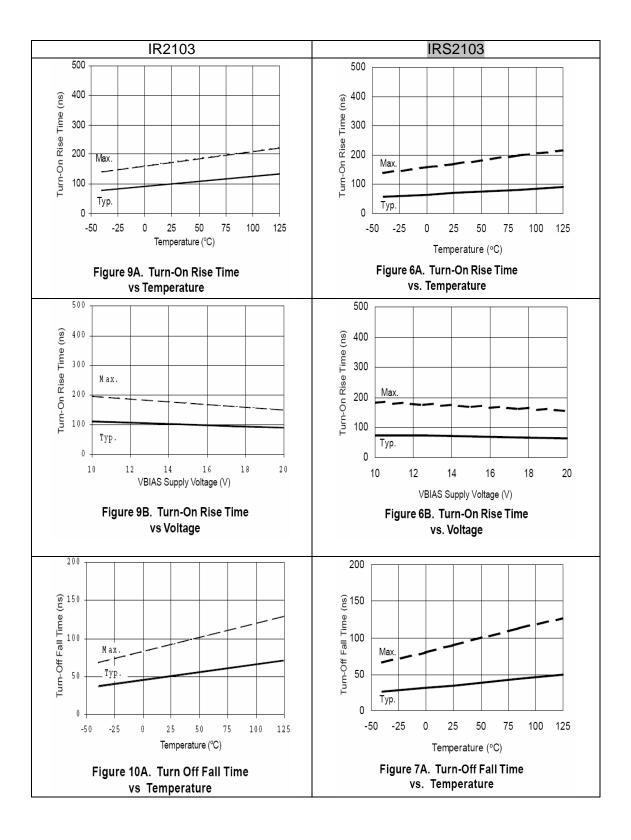
#### With the IRS2103,

- 1.  $V_{IH}$  has been reduced to 2.5 V for better 3.3 V logic compatibility.
- 2. The  $V_{OH}$  and  $V_{OL}$  are tested using a new standardized test condition of Io=2 mA. The output driver's on resistance is lower for IRS2103, which improves immunity against the Miller effect.
- 3. The typical values for  $I_{O+}$  and  $I_{O-}$  are increased, which allows faster switching.

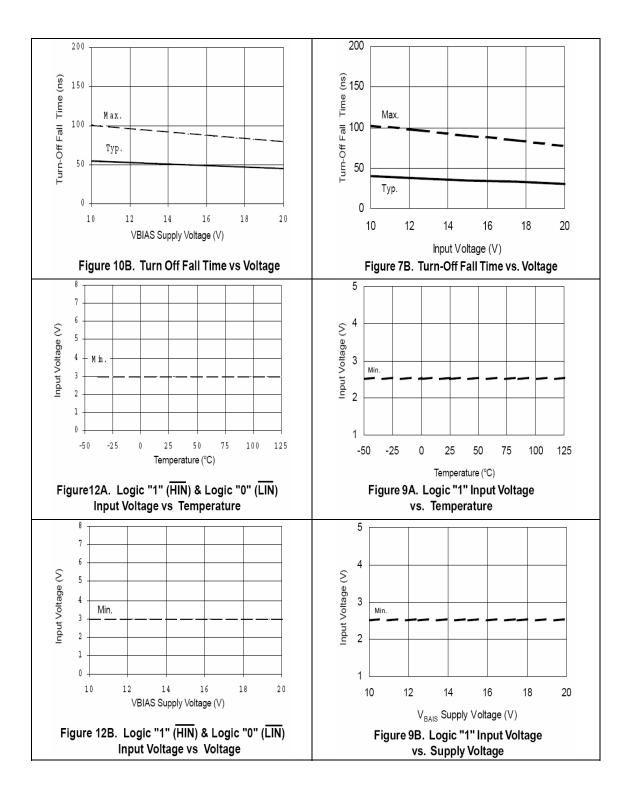
## **Figures**

This figures shown in this section compare figures shown in the IR2103 (left column) and IRS2103 (right column) datasheets. Illustrations that have not changed between the two datasheets have not been included in this section.

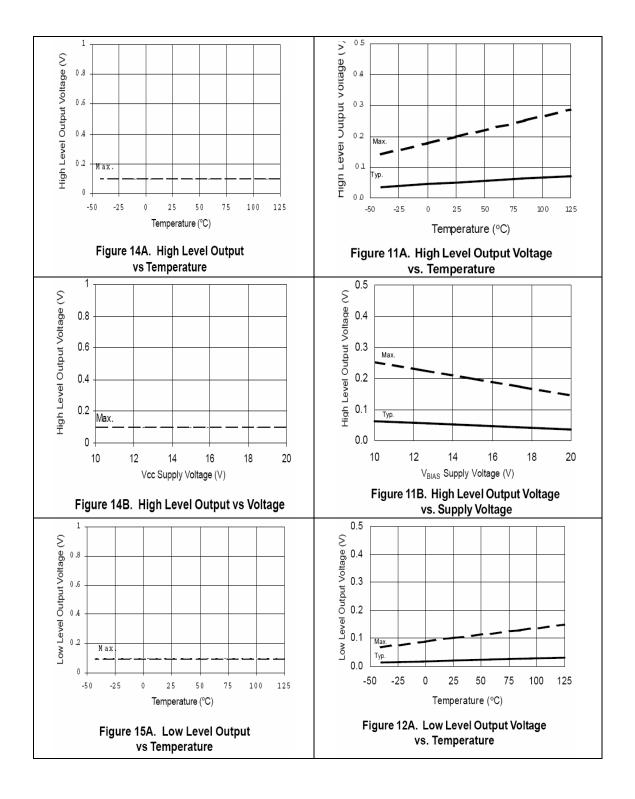




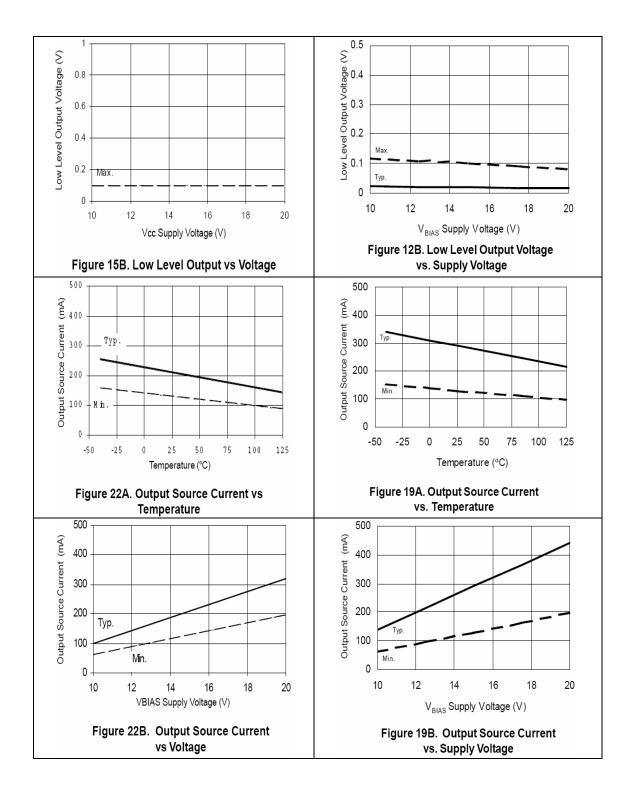




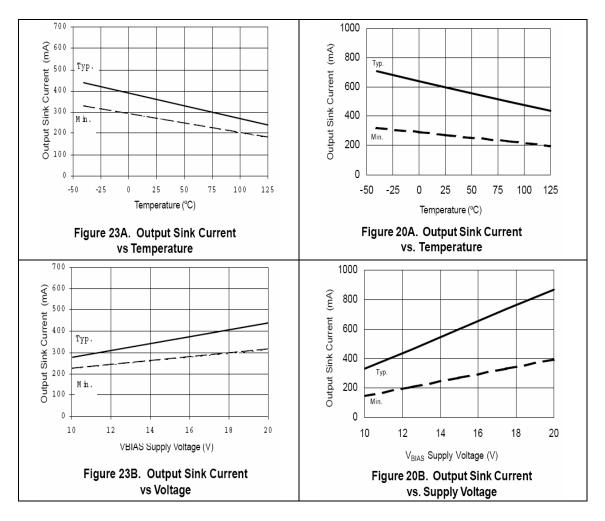












# **Summary**

As shown by this document, the IRS2103 and the IR2103 are very similar with only a few negligible parametric differences.